	- 1 - 1
ΡΛΝ	JIT
	SEMI
	CONDUCTOR

60V P-Channel Enhancement Mode MOSFET

-60 V Current

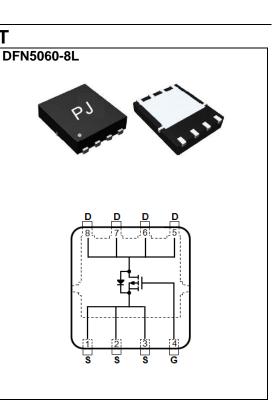
Features

Voltage

- $R_{DS(ON)}$, V_{GS} @-10V, I_D @-8A<48m Ω
- $R_{DS(ON)}$, V_{GS} @-4.5V, I_D @-4A<65m Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 Standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0028 ounces, 0.08 gram



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

-16 A

PARAMETE	R	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage Gate-Source Voltage		V _{DS}	-60	V	
		V _{GS}	<u>+</u> 20		
Continuous Drain Current (Note 4)	T _C =25°C		-16		
	T _c =100°C	I _D	-10	А	
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	-64		
Power Dissipation	T _C =25°C		25	14/	
	T _c =100°C	PD	10	W	
Continuous Drain Current (Note 4)	T _A =25°C		-5	•	
	T _A =70°C	I _D	-4	A	
Power Dissipation	T _A =25°C		2		
	T _A =70°C	PD	1.3	W	
Single Pulse Avalanche Energy (Note 6)		E _{AS}	51	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	R _{θJC}	5	90.444	
	Junction to Ambient	R _{θJA}	62.5	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

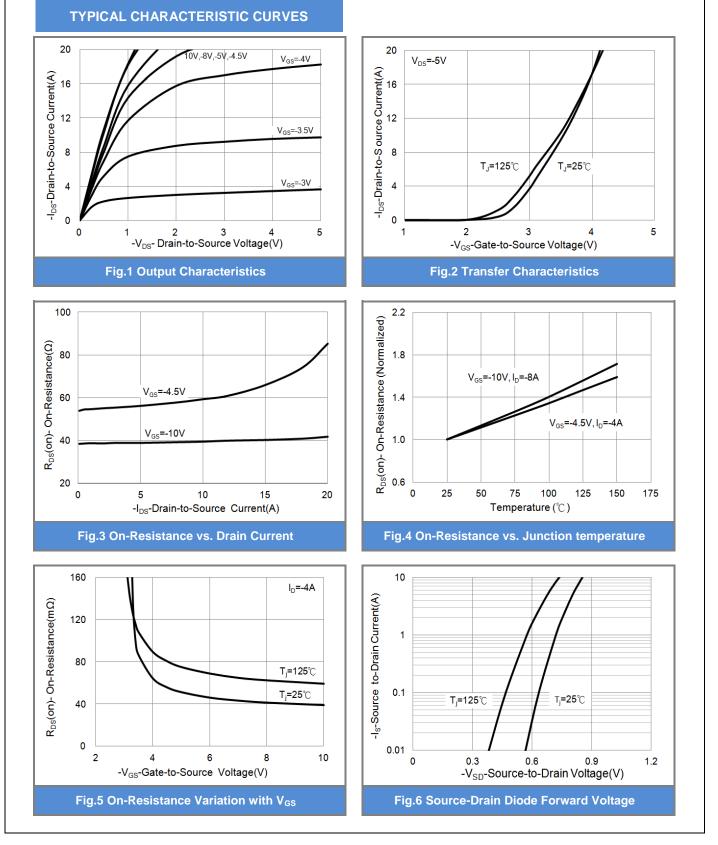
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250$ uA	-1	-1.7	-2.5	
Drain-Source On-State Resistance	D	V _{GS} =-10V, I _D =-8A	-	40	48	mΩ
	R _{DS(on)}	V _{GS} =-4.5V, I _D =-4A	-	55	65	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg	V _{DS} =-30V, I _D =-8A, V _{GS} =-10V ^(Note 3)	-	22	-	nC
Gate-Source Charge	Q _{gs}		-	4.1	-	
Gate-Drain Charge	Q _{gd}		-	5.2	-	
Input Capacitance	Ciss	V _{DS} =-30V, V _{GS} =0V,	-	1256	-	pF
Output Capacitance	Coss		-	87	-	
Reverse Transfer Capacitance	Crss	f=1MHZ	-	59	-	
Turn-On Delay Time	td _(on)	V_{DD} =-30V, I _D =-1A, V_{GS} =-10V, R _G =6Ω (Note 3)	-	13	-	
Turn-On Rise Time	tr		-	42	-	
Turn-Off Delay Time	td _(off)		-	65	-	ns
Turn-Off Fall Time	t _f		-	16	-	
Drain-Source Diode						
Maximum Continuous Drain-Source		I _S			16	
Diode Forward Current	IS		-	-	-16	A
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.72	-1	V

NOTES :

1. Pulse width

- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =32A, V_{DD} =25V, V_{GS} =10V.
- 7. Guaranteed by design, not subject to production testing.

April 01,2019-REV.00

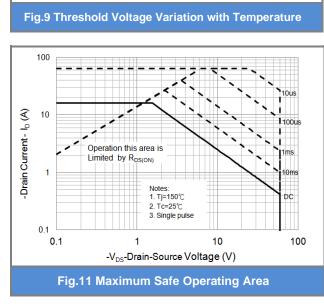


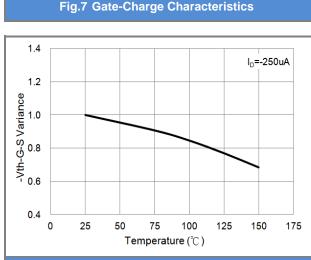
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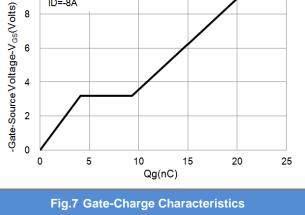


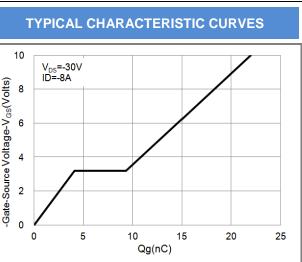
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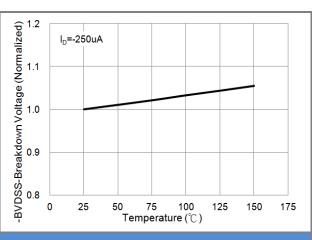














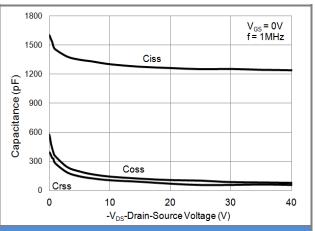
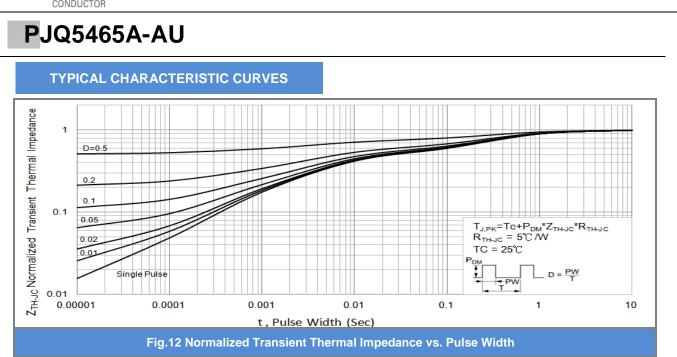


Fig.10 Capacitance vs. Drain-Source Voltage



SEMI

PAN



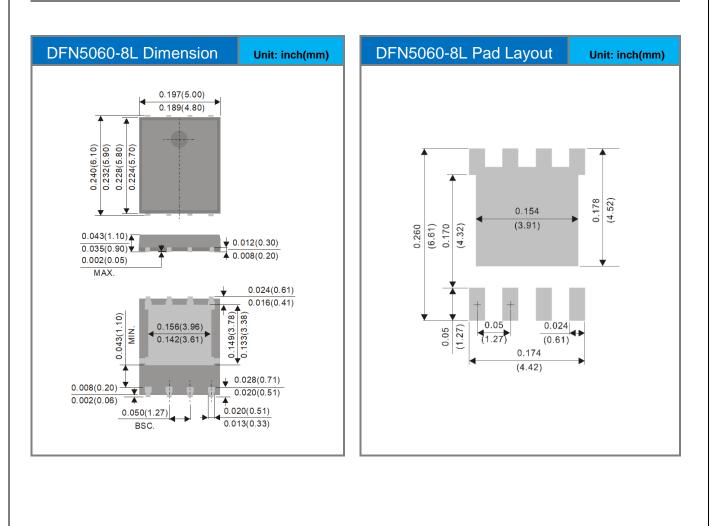




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5465A-AU_R2_000A1	DFN5060-8L	3000pcs / 13" reel	Q5465A	Halogen free

Packaging Information & Mounting Pad Layout





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